

SDB16100PI

Schottky Barrier Rectifier

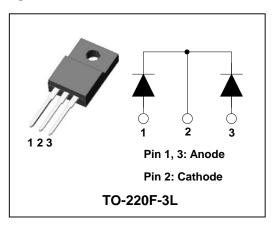
DUAL COMMON CATHODE SCHOTTKY RECTIFIER

Features

- · Low forward voltage drop
- · Low power loss and High efficiency
- · Low leakage current
- · High surge capability
- Full lead (Pb)-free and RoHS compliant device

Applications

- Switching power supplies
- Converter
- Free-wheeling diode
- · Reverse battery protection
- · Power inverters



Product Characteristics

I _{F(AV)}	2 X 8A
V_{RRM}	100V
V _{FM} at 125℃	0.72V
I _{FSM}	180A

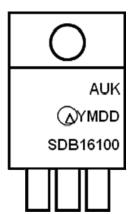
Description

The SDB16100PI Schottky rectifier has been optimized for low reverse leakage at high temperature. Ideally suited for use in low voltage, high frequency switching power supplies, free-wheeling diodes, and polarity protection diodes.

Ordering Information

Device Marking Code		Package	Packaging	
SDB16100PI SDB16100		TO-220F-3L	Tube	

Marking Information



AUK = Manufacture Logo

 Δ = Control Code of Manufacture

YMDD = Date Code Marking

-. Y = Year Code

-. M = Monthly Code

-. D = Daily Code

SDB16100 = Specific Device Code

KSD-D00017-001

Absolute Maximum Ratings (Limiting Values)

Characteristic		Symbol	Value	Unit	
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage		V _{RRM} V _{RWM} V _R	100	V	
Maximum avarage forward restified current	per diode		8	А	
Maximum average forward rectified current	total device	I _{F(AV)}	16		
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode		I _{FSM}	180	А	
Storage temperature range		T _{stg}	-45℃ to +150℃	${\mathbb C}$	
Maximum operating junction temperature		Tj	150	$^{\circ}$ C	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Maximum thermal resistance junction to case	per diode	D	4.0	°C/W
	total device	$R_{th(j-c)}$	3.6	

Electrical Characteristics (Per Diode)

Characteristic	Symbol	Test Condition		Min.	Тур.	Max.	Unit
Peak forward voltage drop	V _{FM} ⁽¹⁾	I _{FM} = 8A	T _j =25℃	ı	1	0.82	V
			T _j =125℃	-	-	0.72	V
Reverse leakage current	I _{RM} ⁽¹⁾	$V_R = V_{RRM}$	T _j =25℃	-		0.1	mA
			T _j =125℃	-		5.0	mA
Junction capacitance	C _j	$V_R = 10V_{DC}$, $f=1MHz$		-	130	-	pF

Note : (1) Pulse test : $t_P \le 380~\mu\text{s}$, Duty cycle $\le 2\%$

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Rating and Characteristic Curves

Fig. 1) Typical Forward Characteristics (Per Diode)

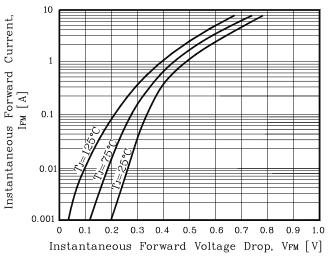


Fig. 2) Typical Reverse Characteristics (Per Diode)

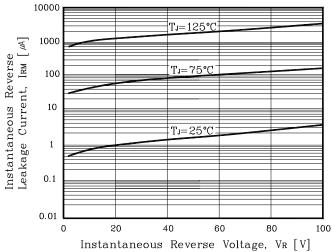


Fig. 3) Maximum Forward Derative Curve (Per Diode)

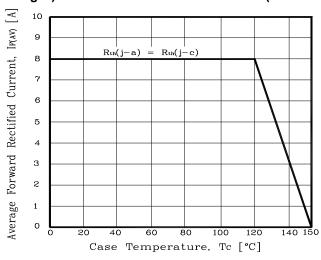


Fig. 4) Forward Power Dissipation (Per Diode)

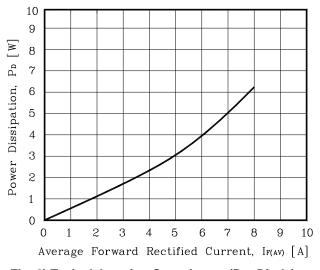


Fig. 5) Maximum Non-Repetitive Peak Forward Surge Current (Per Diode)

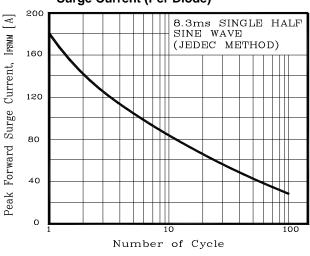
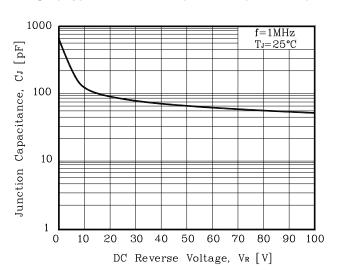


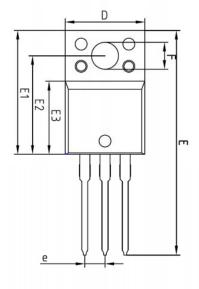
Fig. 6) Typical Junction Capacitance (Per Diode)

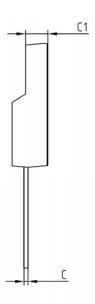


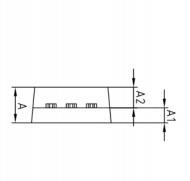
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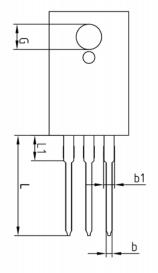
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Package Outline Dimension









		NOTE			
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOIL	
Α	_	_	4.60		
A1	2.45	2.50	2.55		
A2	1.95	2.00	2.05		
b	0.65	0.75	0.85		
b1	1.07	1.27	1.47		
С	0.40	0.50	0.60		
C1	2.70	2.80	2.90		
D	9.90	10.00	10.10		
Ε	28.00	_	28.60		
E1	15.50	15.60	15.70		
E2	12.30	12.40	12.50		
E3	9.15	9.20	9.25		
F	3.30	3.40	3.50		
G	3.10	3.20	3.30		
е	2.54 BSC				
L	12.40	 3.46_BS	13.00		
L1					

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